

20 V, single N-channel Trench MOSFET 30 November 2012

Product data sheet

### 1. Product profile

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### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### **1.2 Features and benefits**

- 2.1 kV ESD protection
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Tin-plated, 100% solderable side pads for optical solder inspection

### 1.3 Applications

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- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portables
- Hard disk and computing power management

### 1.4 Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	20	V
V <sub>GS</sub>	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	10.1	А
Static characte	eristics	·			-		
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 7 A; T <sub>j</sub> = 25 °C		-	19	22	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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# 2. Pinning information

Table 2.	Pinning	information			
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	D	drain		D	
2	D	drain			
3	G	gate		G ( The second s	
4	S	source	3   8   4     Transparent top view   DFN2020MD-6 (SOT1220)     S   017aa		
5	D	drain			
6	D	drain		DFN2020MD-6 (SOT1220)	S 017aaa255
7	D	drain			
8	S	source			

# 3. Ordering information

Table 3. Ordering inf	formation					
Type number	Package					
	Name	Description	Version			
PMPB23XNE	DFN2020MD-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220			

# 4. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB23XNE	1К

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	10.1	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	7	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	4.4	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	24	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[1]	-	1.7	W
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Symbol	Parameter	Conditions		Min	Max	Unit
		T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	3.5	W
		T <sub>sp</sub> = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain	n diode		I.			-
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.9	А
ESD maximu	um rating					
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[2]	-	2100	V

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
 Measured between all pins.

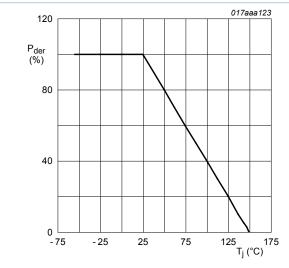


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

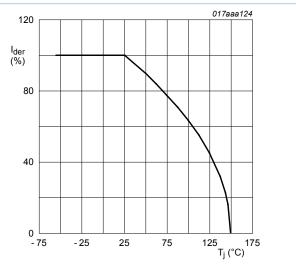


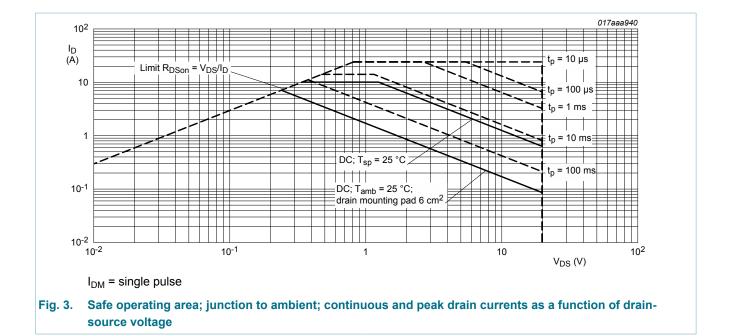
Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

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### 6. Thermal characteristics

Table 6. T	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient			[1]	-	235	270	K/W
	-		[2]	-	67	74	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	33	36	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	5	10	K/W

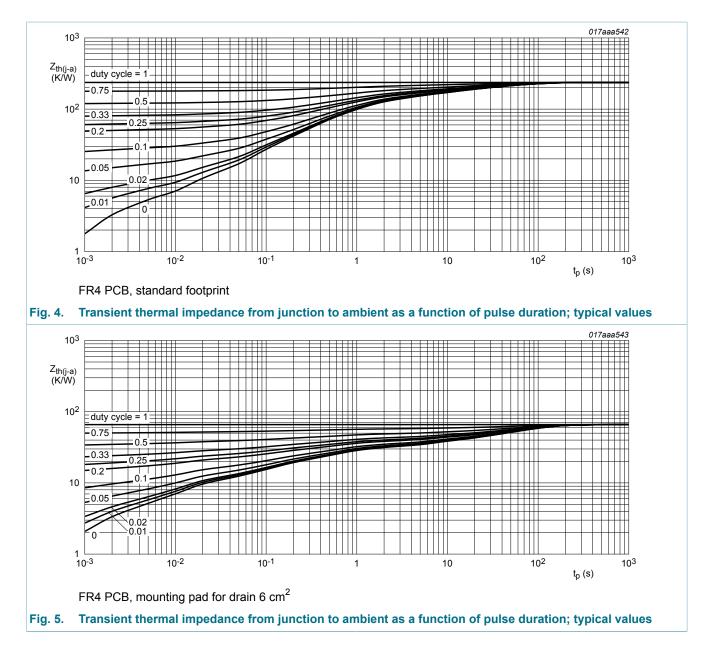
Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
 Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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### 7. Characteristics

Table 7. Characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C		20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = 250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C		0.4	0.65	0.9	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = 20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C		-	-	1	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C		-	-	10	μA
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		$V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 7 A; T <sub>j</sub> = 25 °C	-	19	22	mΩ
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 7 A; T <sub>j</sub> = 150 °C	-	29	34	mΩ
		$V_{GS}$ = 2.5 V; I <sub>D</sub> = 6.1 A; T <sub>j</sub> = 25 °C	-	23	29	mΩ
		$V_{GS}$ = 1.8 V; I <sub>D</sub> = 1.9 A; T <sub>j</sub> = 25 °C	-	31	44	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 7 A; T <sub>j</sub> = 25 °C	-	50	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	-	2.4	-	Ω
Dynamic cl	naracteristics				1	
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 10 V; I <sub>D</sub> = 6 A; V <sub>GS</sub> = 4.5 V;	-	11.6	17	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.4	-	nC
Q <sub>GD</sub>	gate-drain charge	_	-	2.2	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = 10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	1136	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	137	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	112	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 10 V; I <sub>D</sub> = 6 A; V <sub>GS</sub> = 4.5 V;	-	9	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C	-	20	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	31	-	ns
t <sub>f</sub>	fall time		-	32	_	ns

#### Source-drain diode

24

16

8

0

0

I<sub>D</sub> (A)

source-drain voltage

 $V_{SD}$ 

 $I_{S}$  = 1.9 A;  $V_{GS}$  = 0 V;  $T_{j}$  = 25 °C

1.2

V

0.6

-

017aaa941 017aaa942 10<sup>-2</sup> -4.5 V 1.7 V I<sub>D</sub> (A) 25V 10<sup>-3</sup> 1.6 V min tvp max 1.5 V 10-4 1.4 V 1.3 V 10<sup>-5</sup> V<sub>GS</sub> = 1.2 V 10<sup>-6</sup> 1 2 0.0 0.4 0.8 3 1.2 4 V<sub>DS</sub> (V) V<sub>GS</sub> (V) T<sub>i</sub> = 25 °C T<sub>i</sub> = 25 °C; V<sub>DS</sub> = 5 V Subthreshold drain current as a function of Output characteristics: drain current as a Fig. 7. function of drain-source voltage; typical values

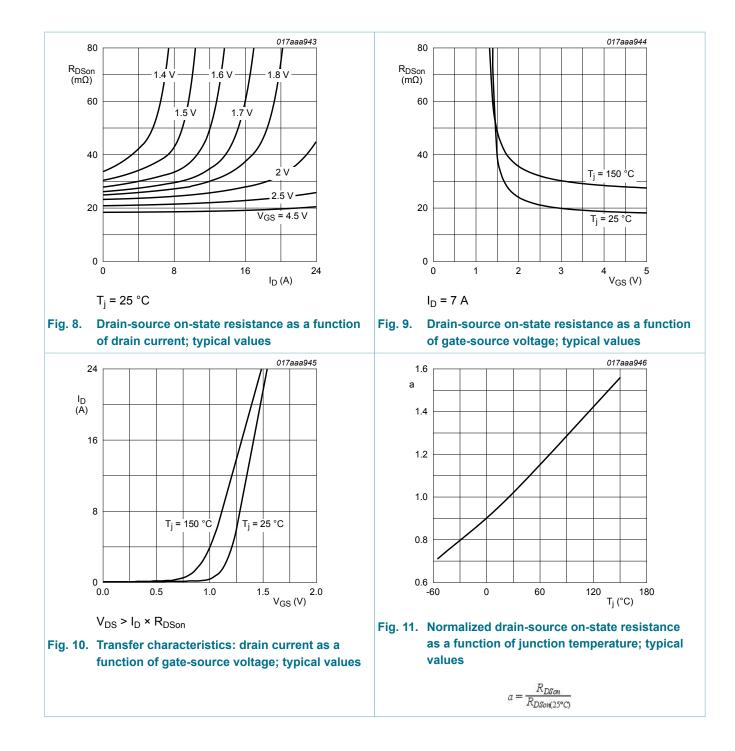
gate-source voltage All information provided in this document is subject to legal disclaimers.

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Fig. 6.

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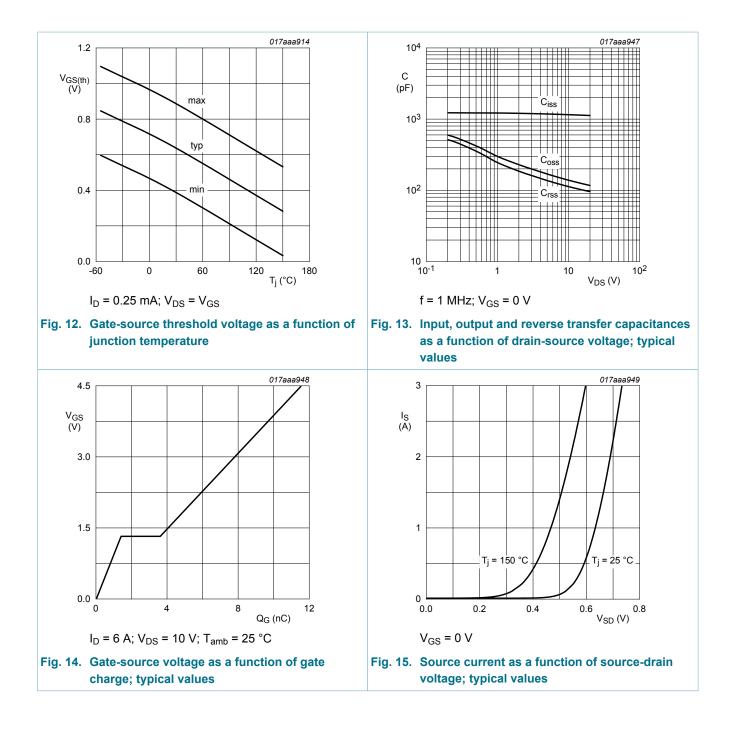
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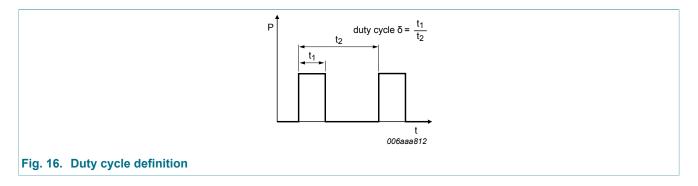


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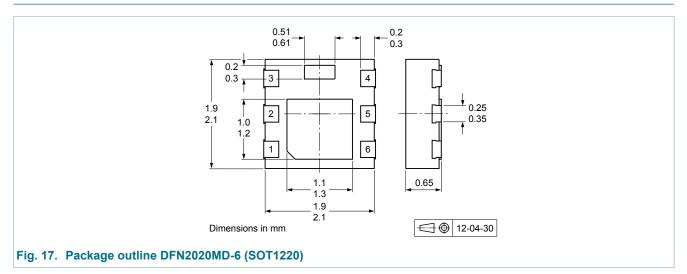
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### 8. Test information

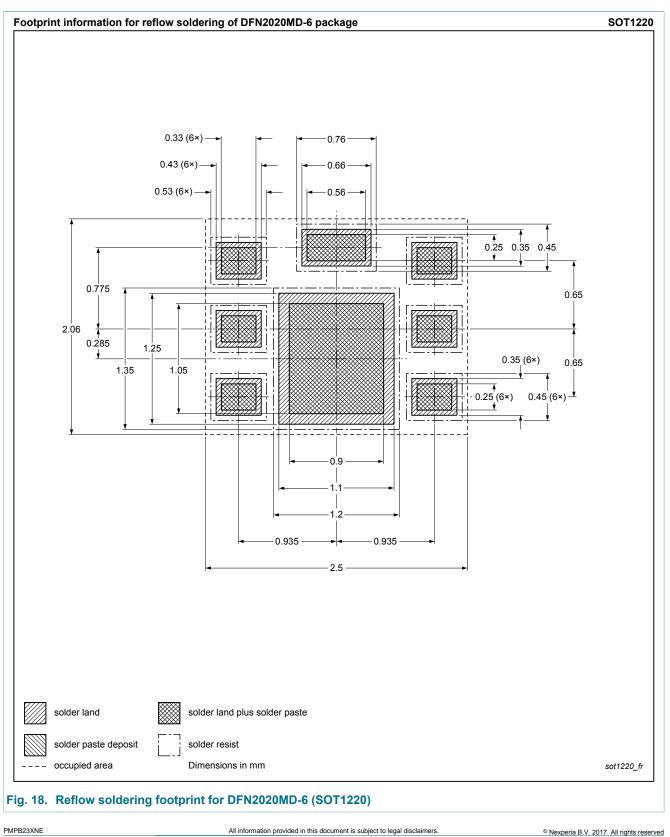


# 9. Package outline



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### **10. Soldering**



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### 20 V, single N-channel Trench MOSFET

# **11. Revision history**

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PMPB23XNE v.1	20121130	Product data sheet	-	-	

#### 20 V, single N-channel Trench MOSFET

### 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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